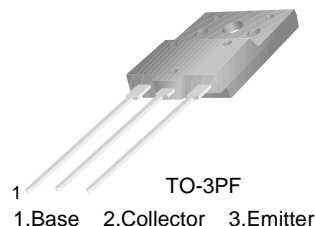


# KSC5803

KSC5803

## High Voltage Color Display Horizontal Deflection Output (No Damper Diode)

- High Breakdown Voltage :  $BV_{CBO}=1500V$
- High Speed Switching :  $t_F=0.1\mu s$  (Typ.)
- Wide S.O.A
- For C-Monitor(85KHz)



## NPN Triple Diffused Planar Silicon Transistor

### Absolute Maximum Ratings $T_C=25^\circ C$ unless otherwise noted

| Symbol    | Parameter                                  | Value      | Units      |
|-----------|--|------------|------------|
| $V_{CBO}$ | Collector-Base Voltage                     | 1500       | V          |
| $V_{CEO}$ | Collector-Emitter Voltage                  | 800        | V          |
| $V_{EBO}$ | Emitter-Base Voltage                       | 6          | V          |
| $I_C$     | Collector Current (DC)                     | 12         | A          |
| $I_{CP}$  | Collector Current (Pulse)                  | 24         | A          |
| $P_C$     | Collector Dissipation ( $T_C=25^\circ C$ ) | 70         | W          |
| $T_J$     | Junction Temperature                       | 150        | $^\circ C$ |
| $T_{STG}$ | Storage Temperature                        | - 55 ~ 150 | $^\circ C$ |

### Electrical Characteristics $T_C=25^\circ C$ unless otherwise noted

| Symbol                 | Parameter                            | Test Condition  | Min.      | Typ. | Max.      | Units   |
|------------------------|--------------------------------------|---|-----------|------|-----------|---------|
| $I_{CES}$              | Collector Cut-off Current            | $V_{CE} = 1400V, V_{BE}=0$                            |           |      | 1         | mA      |
| $I_{CBO}$              | Collector Cut-off Current            | $V_{CE}= 800V, I_E = 0$                               |           |      | 10        | $\mu A$ |
| $I_{EBO}$              | Emitter Cut-off Current              | $V_{EB} = 4V, I_C = 0$                                |           |      | 1         | mA      |
| $h_{FE1}$<br>$h_{FE2}$ | DC Current Gain                      | $V_{CE} = 5V, I_C = 1A$<br>$V_{CE} = 5V, I_C = 8A$    | 15<br>5.5 |      | 40<br>8.5 |         |
| $V_{CE(sat)}$          | Collector-Emitter Saturation Voltage | $I_C = 8A, I_B = 2A$                                  |           |      | 3         | V       |
| $V_{BE(sat)}$          | Base-Emitter Saturation Voltage      | $I_C = 8A, I_B = 2A$                                  |           |      | 1.5       | V       |
| $t_{STG}$              | Storage Time                         | $V_{CC} = 200V, I_C = 7A$                             |           |      | 4         | $\mu s$ |
| $t_F$                  | Fall Time                            | $I_{B1} = 1.4A, I_{B2}= - 2.8A$<br>$R_L = 28.6\Omega$ |           |      | 0.3       | $\mu s$ |

# Typical Characteristics

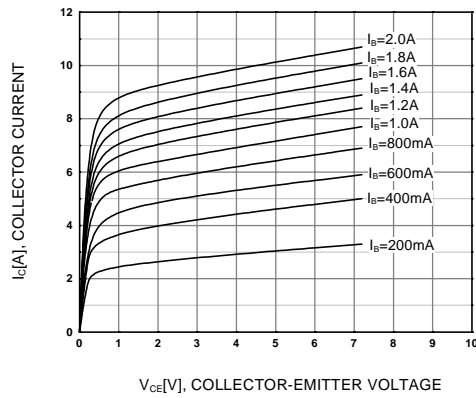


Figure 1. Static Characteristic

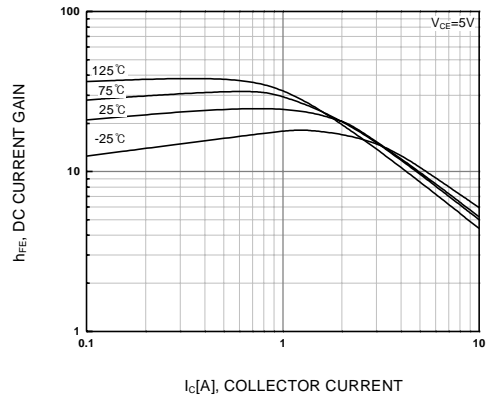


Figure 2. DC current Gain

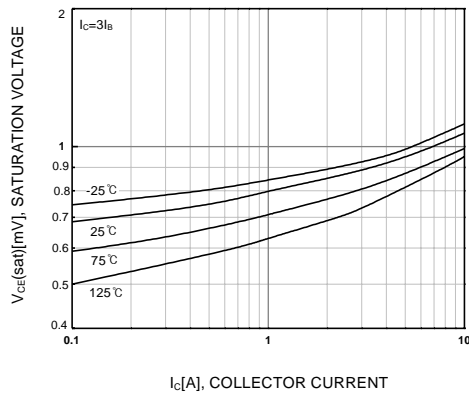


Figure 3. Base-Emitter Saturation Voltage

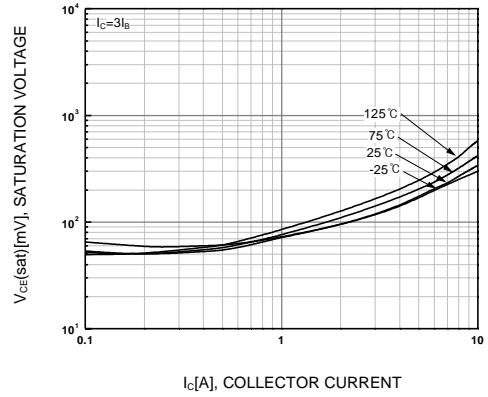


Figure 4. Collector-Emitter Saturation Voltage 1

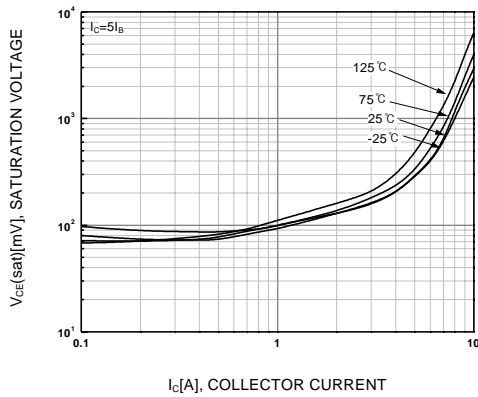


Figure 5. Collector-Emitter Saturation Voltage 2

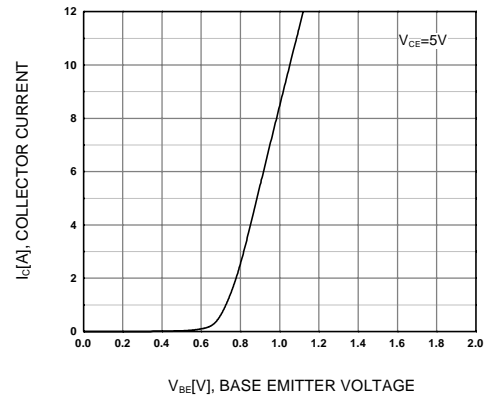


Figure 6. Base-Emitter On Voltage

## Typical Characteristics (Continued)

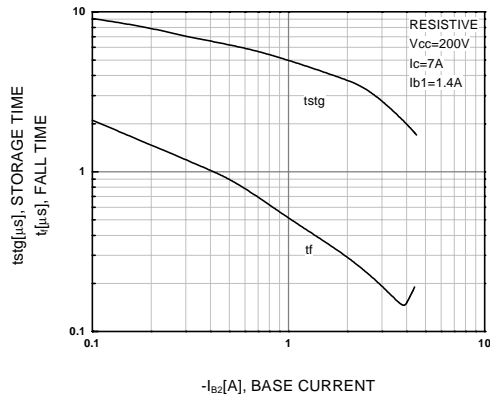


Figure 7. Switching Time

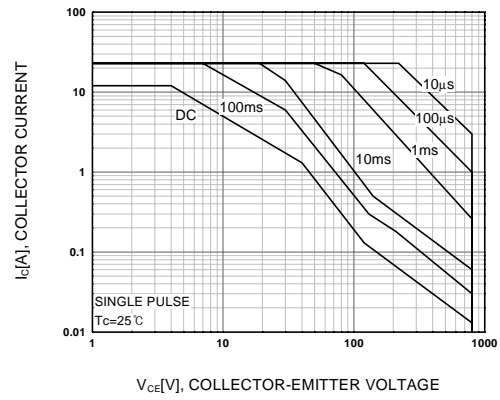


Figure 8. Safe Operating Area

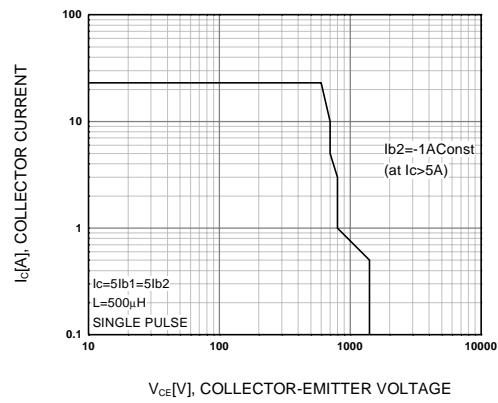


Figure 9. Reverse Bias Safe Operating Area

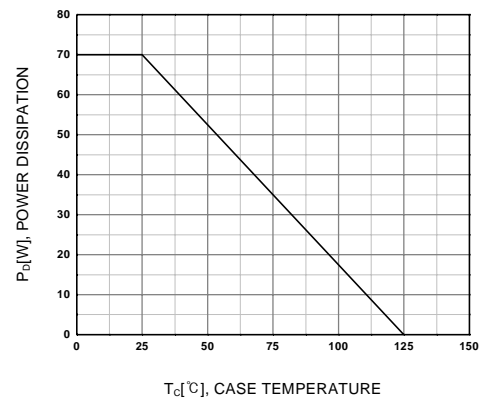
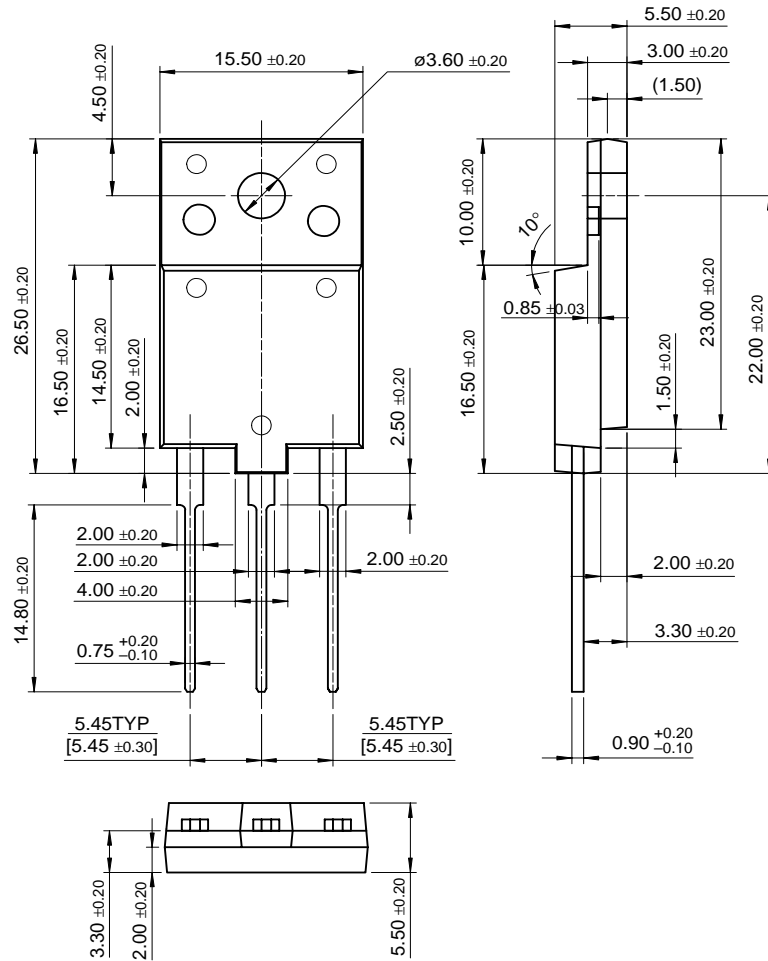


Figure 10. Power Derating

# Package Dimensions

## TO-3PF



Dimensions in Millimeters

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| CROSSVOLT™           | POP™          | UHC™        |
| E <sup>2</sup> CMOS™ | PowerTrench®  | VCX™        |
| FACT™                | QFET™         |             |
| FACT Quiet Series™   | QS™           |             |
| FAST®                | Quiet Series™ |             |
| FASTr™               | SuperSOT™-3   |             |
| GTO™                 | SuperSOT™-6   |             |

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